GUJARAT TECHNOLOGICAL UNIVERSITY BE –SEMESTER 1&2(NEW SYLLABUS)EXAMINATION- WINTER 2018

Subject Code: 3110018		Code: 3110018 Date: 04-01-	Date: 04-01-2019	
Subject Name: Physics Time: 10:30 am to 01:00 pm Total Ma			rks: 70	
Instru	uction 1. 2. 3.	s: Attempt all questions. Make suitable assumptions wherever necessary. Figures to the right indicate full marks.		
Q.1	(a) (b) (c)	Give assumptions of classical free electron theory. Explain mechanism of superconductivity. What is photovoltaic effect. Explain construction and working of solar cell.	03 04 07	
Q.2	(a) (b) (c)	Give difference between N type and P type semiconductors. Derive an expression for joint density of states. Explain Kronig Penney model in detail. OR	03 04 07	
Q.3	(c) (a) (b) (c)	Explain properties of superconductors. What are hot probe method. Explain fermi levels. Explain classification of materials as conductors, insulators and semiconductors.	07 03 04 07	
Q.3	(a) (b)	OR Give difference between intrinsic and extrinsic semiconductors. Explain drift and diffusion current.	03 04	
Q.4	(c) (a) (b) (c)	Explain direct and indirect band gap with E-k diagrams. Define superconductivity and critical temperature. Discuss fermi golden rule. Explain diffusion mechanism in detail.	07 03 04 07	
Q.4	(c) (a) (b) (c)	OR Define radiative and non-radiative transitions. Explain emission and absorption. Explain experimental procedure for DLTS.	03 04 07	
Q.5	(a) (b) (c)	The critical temperature of Nb is 9.15 K. At zero kelvin, the critical field is 0.196 T. Calculate the critical field at 6 K. Explain Drude model. Why two probe method for resistivity measurement failed and hence explain four probe method.	03 04 07	
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Q.5	(a) (b) (c)	Give success and drawback of classical free electron theory. Derive expression of electron concentration in conduction band. Discuss UV – VIS method for band gap measurement of semiconductors.	03 04 07	
